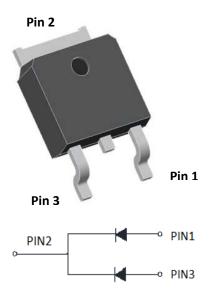


MBR1045CDS





Schottky Diodes

Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

• Package: TO-252

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

 Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102

• Polarity: As marked

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR1045CDS
Device marking code			MBR1045CDS
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, T _C =117°C	lo	Α	10
Surge(Non-repetitive)Forward Current @60H _Z half sine-wave, 1 cycle, T _a =25℃	IFSM	Α	100
Current Squared Time @1ms≤t≤8.3ms Tj=25°C,	l²t	A ² s	41
Storage Temperature	T _{stg}	$^{\circ}$	-55 ~ + 150
Junction Temperature	Tj	$^{\circ}$	-55 ~ +150

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

=Elocation official (Ta 25 c offices carefules opening)				
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR1045CDS
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=5.0A	0.65
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1		VRM=VRRM T _a =25℃	0.2
	IRRM2	mA	VRM=VRRM T _a =100°C	20

Note1:Pulse test:300uS pulse widh,1% duty cycle

Note2:Pulse test:pulse widh 40mS

MBR1045CDS

Thermal Characteristics $(T_a=25^{\circ}\mathbb{C} \text{ Unless otherwise specified})$

PA	SYMBOL	UNIT	MBR1045CDS	
Thermal Resistance	Between junction and case	RøJ-C	°C /W	5.0

■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR1045CDS	Approximate 0.32	2500	2500	25000	Reel

■Characteristics (Typical)

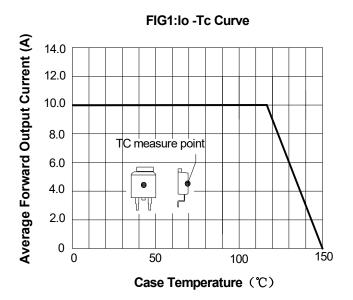
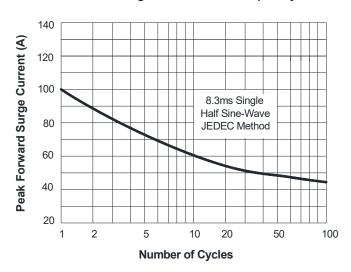
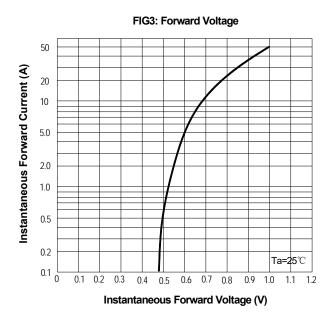
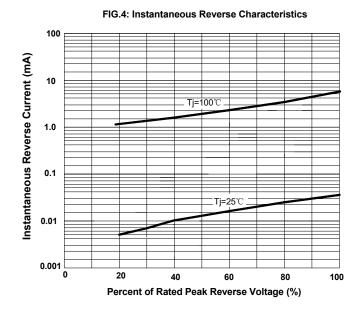


FIG2:Surge Forward Current Capability

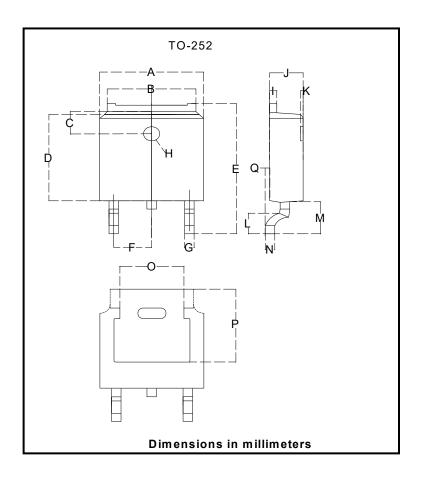






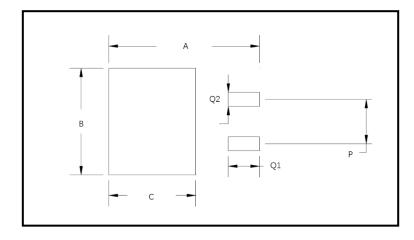


■Outline Dimensions



TO-252			
Dim	Min	Max	
Α	6.500	6.700	
В	5.100	5.460	
С	1.400	1.800	
D	6.000	6.200	
Е	10.000	10.400	
F	2.166	2.366	
G	0.660	0.860	
Н	Ф1.050	Ф1.350	
I	0.460	0.580	
J	2.200	2.400	
K	0	0.300	
L	0.890	2.290	
М	2.730	3.080	
N	0.430	0.580	
0	4.20	4.95	
Р	5.15	5.45	
Q	0	0.2	

■ Suggested Pad Layout



Dim	Millimeters
Α	11.4
В	6.74
С	6.23
Р	4.56
Q1	2.28
Q2	1.52



MBR1045CDS

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